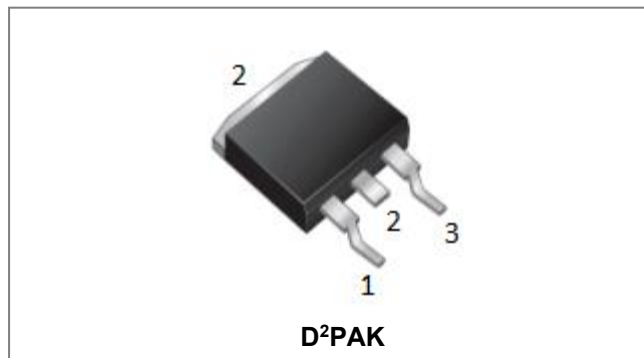


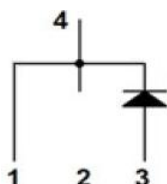
SK1840D SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	40	V
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _c =105°C, rectangular wave form	18	A
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	280	A

Electrical Characteristics:

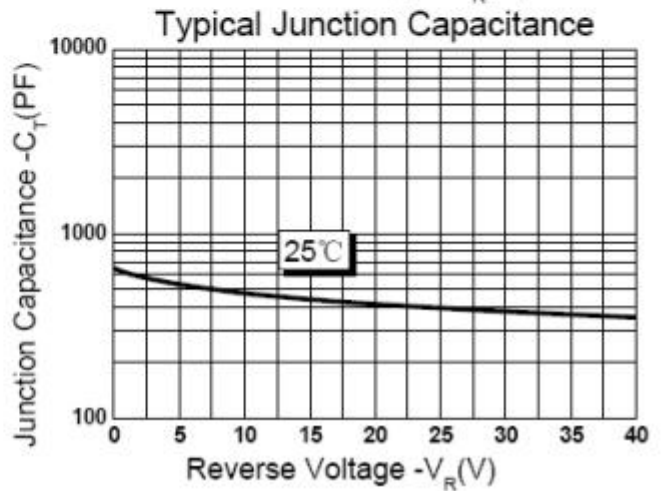
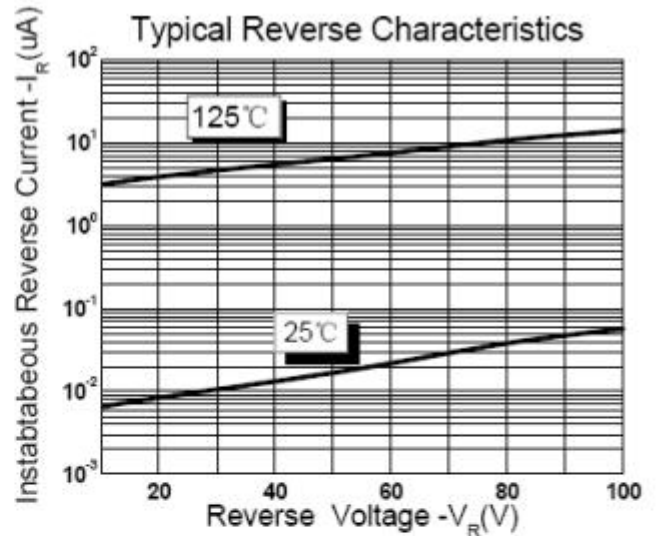
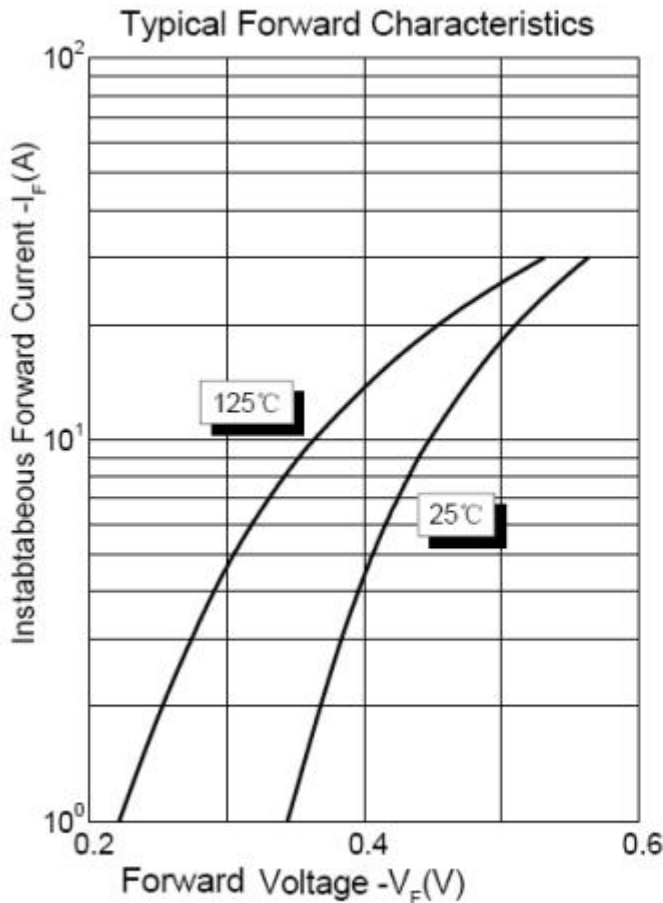
Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 5.0A, Pulse, T _J = 25 °C	0.41	0.50	V
	V _{F2}	@ 18A, Pulse, T _J = 25 °C	0.50	0.58	V
Reverse Current *	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.0001	0.5	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	0.006	30	mA
Junction Capacitance	C _T	@V _R = 5.0V, T _C = 25 °C f _{SIG} = 1MHz	500	800	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

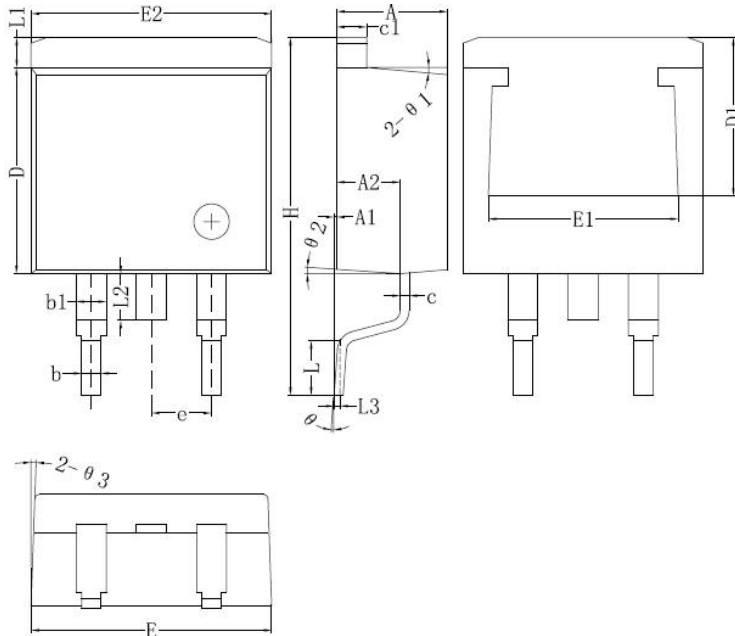
* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-	-55 to +150	$^{\circ}\text{C}$
Typical Thermal Resistance Junction to Case	$R_{\theta\text{JC}}$	-	6	$^{\circ}\text{C/W}$
Approximate Weight	wt	-	1.85	g
Case Style	D2PAK			

Ratings and Characteristics Curves



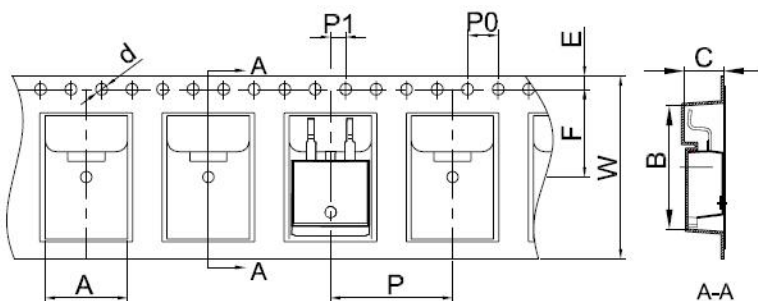
Mechanical Dimensions D²PAK


Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	4.47	4.70	4.85
A1	0	0.10	0.25
A2	2.59	2.69	2.89
b	0.71	0.81	0.96
b1	1.17	1.27	1.37
c	0.31	0.38	0.61
c1	1.17	1.27	1.37
D	8.50	8.70	8.90
D1	6.40		
E	10.01	10.16	10.31
E1	7.6		
E2	9.98	10.08	10.31
e		2.54	
H	14.6	15.1	15.6
L	2.00	2.30	2.74
L1	1.12	1.27	1.42
L2	1.30		2.20
L3		0.25BSC	
e	0	-	8°
e1		5°	
e2		4°	
e3		4°	

Ordering Information

Device	Package	Shipping
SK1840D	D ² PAK (Pb-Free)	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

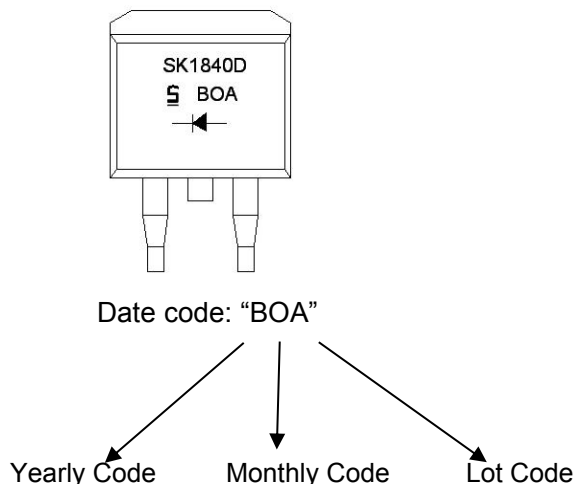
Carrier Tape & Reel Specification D²PAK


SYMBOL	Millimeters	
	Min.	Max.
A	10.70	10.90
B	16.03	16.23
C	5.11	5.31
d	1.45	1.65
E	1.65	1.85
F	11.40	11.60
P0	3.90	4.10
P	15.90	16.10
P1	1.90	2.10
W	23.90	24.30

Marking Diagram

First row: part number
Second row: the Semikron logo and date code
Third row: topology

For example,



Date Code Description

Yearly Code

Year	code	Year	code	Year	code	Year	code	Year	code	Year	code
1998	K	2003	R	2008	W	2013	D	2018	K	2023	R
1999	L	2004	S	2009	X	2014	E	2019	L	2024	S
2000	M	2005	T	2010	A	2015	F	2020	M	2025	T
2001	N	2006	U	2011	B	2016	G	2021	N	2026	U
2002	P	2007	V	2012	C	2017	H	2022	P	2027	V

Monthly Code

Month	January	February	March	April	May	June
code	1	2	3	4	5	6
Month	July	August	September	October	November	December
code	7	8	9	O	N	D

Lot Code

Lot number is from 0 to 9 and A to Z.

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